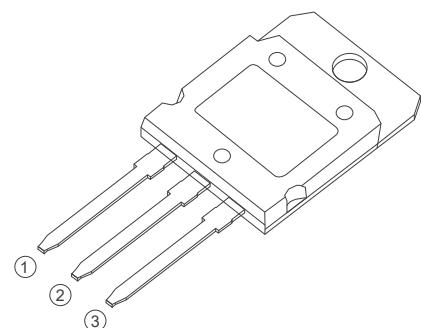


IT(RMS)		100A
VDRM/VRRM	BAT100-1200	1200V
	BAT100-1600	1600V
VTM		1.5V



## FEATURES

IT(RMS): 100A

VGT: 1.3 V

ITO-247 Insulated

VDRM VRRM: 1200V~1600V

High Junction Temperature

Good Commutation Performance

High dV/dt and dI/dt

## APPLICATIONS

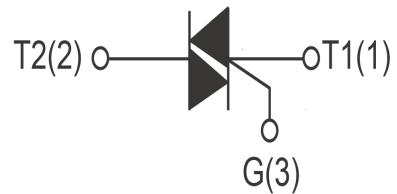
Heater Control

Motor Speed Controller

Washing machine

Vacuums

Solid state relay



## Absolute Maximum Ratings (Tj=25°C unless otherwise specified)

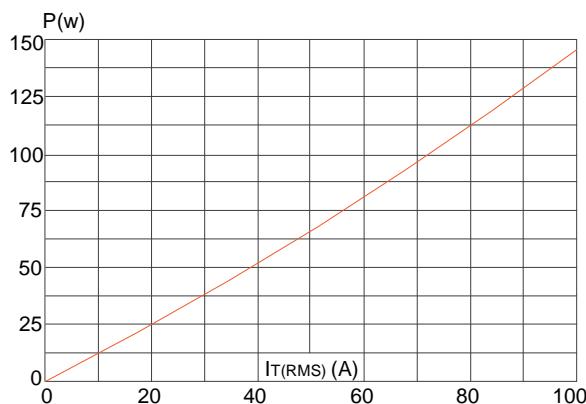
Symbol	Parameter	Conditions	Ratings	Unit
VDRM VRRM	Repetitive Peak Off-State Voltage	BTA100-1200B	1200	V
		BTA100-1600B	1600	
IT(RMS)	R.M.S On-State Current	ITO-247(lns) Tc=70°C	100	A
ITSM	Surge On-State Current	Tp=20ms	1100	A
I <sup>2</sup> t	I <sup>2</sup> t for fusing	Tp=10ms	5500	A <sup>2</sup> s
PG(AV)	Average Gate Power Dissipation	Tj=125°C	2	W
IGM	Peak Gate Current	Tj=125°C	8	A
PGM	Peak Gate power		10	W
Tj	Operating Junction Temperature		~40~125	°C
TSTG	Storage Temperature		~40~150	

**Electrical Characteristics** ( $T_j=25^\circ\text{C}$  unless otherwise specified)

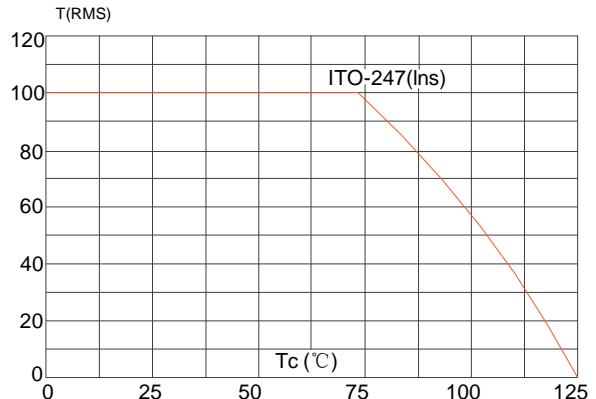
Symbol	Parameter	Test Conditions		Value	Unit	
IDRM	Repetitive Peak Off-State Current	$T_j=25^\circ\text{C}$		20	uA	
		$T_j=125^\circ\text{C}$		12	mA	
IRRM	Repetitive Peak Reverse Current	$T_j=25^\circ\text{C}$		20	uA	
		$T_j=125^\circ\text{C}$		12	mA	
VTM	Forward "on" voltage	$IT=80\text{A}, tp=380\text{us}, T_j=25^\circ\text{C}$		$\leq 1.5$	V	
VGT	Gate trigger voltage	$VD=12\text{V}, RL=33\Omega$		$\leq 1.3$	V	
di/dt	VD=2/3VDRM Gate Open, $T_j=125^\circ\text{C}$ I,II,III,IV	$F=100\text{Hz}, IG=2\times IGT, tr \leq 100\text{ns}$		100	A/us	
IGT	Gate trigger current	I,II,III	$VD=12\text{V}, RL=33\Omega$	$\leq 50$	mA	
IH	Holding current	$IT=100\text{mA}$		$\leq 100$		
VGD	Gate non-trigger voltage	$VD=VDRM, TJ=125^\circ\text{C}, RL=3.3K\Omega$		0.2	V	
dv/dt	Critical-rate of rise of commutation voltage	$TJ=125^\circ\text{C}, VD=2/3VDRM, Gate open circuit$		$\geq 1500$	V/us	
Rth(j-c)	Thermal resistance	Junction to case	ITO-247(Ins)	0.3	$^\circ\text{C}/\text{W}$	

**FIG1**

Maximum power dissipation versus RMS on-state current

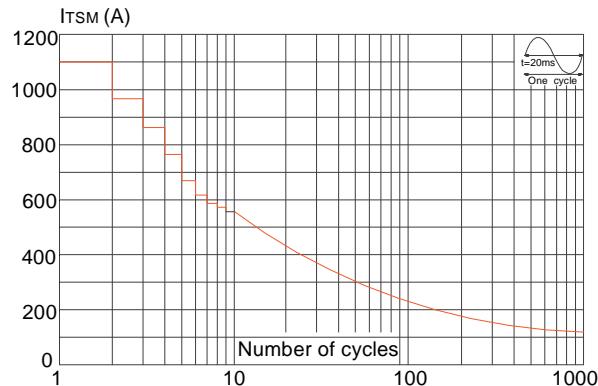
**FIG2**

RMS on-state current versus case temperature

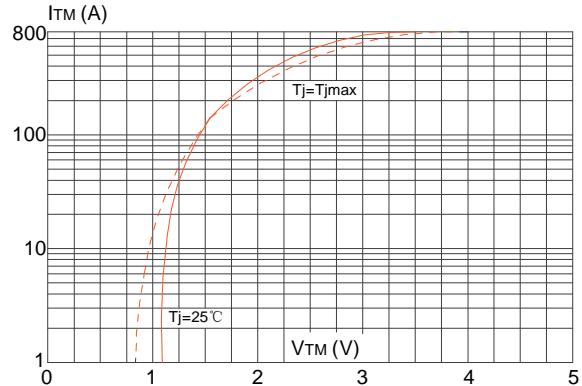


**FIG3**

Surge peak on-state current versus number of cycles


**FIG4**

On-state characteristics (maximum values)


**FIG5**

Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 20ms$ , and corresponding value of  $\int^t dt$  ( $dl/dt < 100A/\mu s$ )

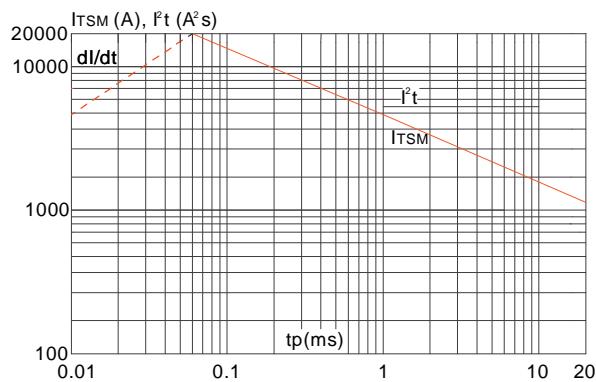
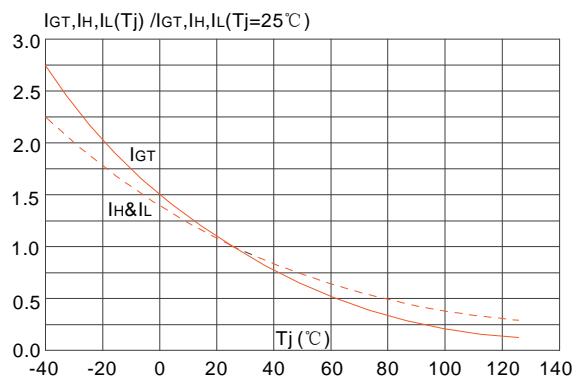
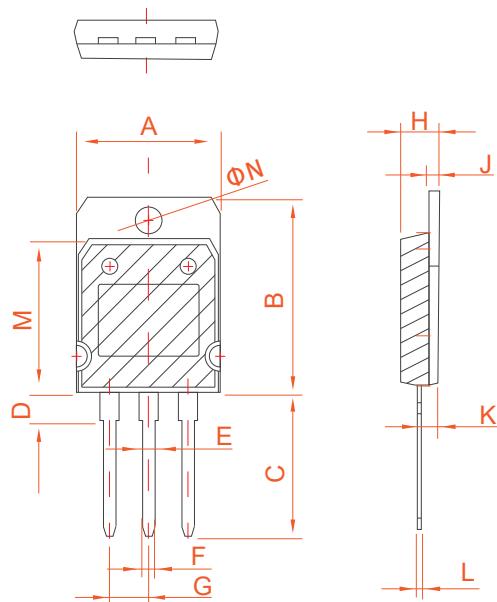

**FIG6**

FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature



## PACKAGE MECHANICAL DATA



ITO-247 (Ins)

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	19.7	19.9	20.1	0.776	0.783	0.791
B	26.9	27.1	27.3	1.059	1.067	1.075
C	19.4	19.9	20.4	0.764	0.783	0.803
D	3.80	3.90	4.00	0.150	0.154	0.157
E	2.56	2.66	2.76	0.101	0.105	0.109
F	1.66	1.76	1.86	0.065	0.069	0.073
G		5.45			0.215	
H	5.05	5.10	5.50	0.199	0.201	0.217
J	1.45	1.50	1.55	0.057	0.059	0.061
K	2.20	2.30	2.40	0.087	0.091	0.094
L	0.60	0.70	0.80	0.024	0.028	0.031
M	21.2	21.3	21.4	0.835	0.839	0.843
N	3.20	3.30	3.40	0.126	0.130	0.134